# **Product Samples**

## **ATP1009: Polyimide Filled Vias**

Applied Thin-Film Products (ATP) is pleased to provide ceramic thin-film samples for your evaluation.

TaN/TiW/Au metalization with polyimide filled, conductive, plated-thru- $CO_2$  laser drilled via holes in Aluminum Oxide (Al<sub>2</sub>O<sub>3</sub>). Polyimide is used as a non-conductive plug for via hole assemblies. Will prevent epoxy and eutectic solders from reaching the surface of the circuit while keeping continuity between back side and front side surfaces.

#### **Material Specifications**

#### **Asfired Superstrate 996 Aluminum Oxide**

Properties	Values
Chemical Composition	Al <sub>2</sub> O <sub>3</sub>
Purity	99.6%
Color	White
Nominal Density	3.88g/cm <sup>3</sup>
Surface Finish (Asfired)	3μ"(76.2nm)
Camber	0.002" (0.0508mm)
Thickness	0.015" (0.381mm)*
Thickness Tolerance (±)	0.001" (0.0254mm)
Coefficient of Thermal Expansion (CTE)	7.0-8.3 x 10 <sup>-6</sup> (25-1000°C)
Thermal Conductivity 100°C	26.9 Watts/m°K
Dielectric Constant 1 MHz	9.9 @ 1 MHz ±0.1
Dielectric Constant 10 GHz	9.7 @ 10 GHz ±0.1
Dissipation Factor (Loss Tangent)	0.0001 @ 1 MHz
Hardness (Rockwell)	87
Flexural Strength	90K (10 <sup>-3</sup> ) lbs/in <sup>2</sup> (620Mpa)
Compressive Strength	54 x 10 <sup>-3</sup> M lbs/in <sup>2</sup>
Grain Size	< 1.0µm

Material specifications provided by Coors Ceramic Company

ATP offers build-to-print service for a wide range of materials and metalization schemes. ATP fabricates circuits on substrates from As-Fired Alumina to Beryllium Oxide to Fused Silica, even Silicon. Metalizations range from the standard Tan/TiW/Au to films including Nickel, Palladium, or Titanium.

ATP1009: Material is 15 mil As-Fired  $Al_2O_3$  TaN Resistors = 50 Ohms per Square

TiW = 400-800 Ångströms Au =  $120\mu$ " minimum

#### **Sample Provided**



### **Physical Properties of Polyimide**

Manufactured according to Mil Spec Mil-I-45208

Properties	Value
Max. Use Temp.	2800°F (1500°C)
Base	Alumina Oxide
Compressive Strength	4200 psi
Flexural Strength	1900 psi
Dielectric Strength	125 Volts/mil
Volume Resistance	10 <sup>8</sup> Ohm cm
Thermal Conductivity	15 BTU in/hr/°F ft²
Thermal Expansion	4.0 x 10 <sup>-6</sup> /°F
Components	2.0
Mix Ratio	100 to 30 (by weight)
Consistency	Paste

At ATP, we constantly evolve our processing and material capabilities to reflect our customer's changing needs. If you have a circuit requirement that is out of the "normal" thin-film type, please contact ATP at 1.510.661.4287 or visit our website at www.thinfilm.com. ATP would enjoy discussing your application with you and working to develop a solution.





